

<b>Notice of References Cited</b>	Application/Control No. 09/840,545	Applicant(s)/Patent Under Reexamination TSAI, ROGER S.	
	Examiner Hugh Jones	Art Unit 2128	Page 1 of 1

**U.S. PATENT DOCUMENTS**

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
	A	US-			
	B	US-			
	C	US-			
	D	US-			
	E	US-			
	F	US-			
	G	US-			
	H	US-			
	I	US-			
	J	US-			
	K	US-			
	L	US-			
	M	US-			

**FOREIGN PATENT DOCUMENTS**

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
	N					
	O					
	P					
	Q					
	R					
	S					
	T					

**NON-PATENT DOCUMENTS**

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	Rein et al.; A semi-physical bipolar transistor model for the design of very high frequency analog ICs; IEEE Proc. Bipolar/BiCMOS ckts & Tech. Meeting; pp. 217-220; 1992.
	V	Ramakrishna et al.; HEMT modeling using semi-physical expressions for the equilibrium space-charge parameters of the modulation-doped heterojunction; IEE Proc. Ckts, Dev & Sys.; pp. 211-214; 8/1999.
	W	
	X	

\*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)  
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.